

The distance s is given by

$$s = \sqrt{h^2 + (a/2)^2}$$

Coulomb's law for charges q_1 and q_2 is

$$\mathbf{F} = \mathbf{k}_0 \, \frac{\mathbf{q}_1 \mathbf{q}_2}{\mathbf{r}^2}$$

which gives the magnitude of the force on +q due to +Q and -Q

$$|\mathbf{F}_{+Q}| = |\mathbf{F}_{-Q}| = k_0 \frac{qQ}{h^2} = k_0 \frac{qQ}{[s^2 + (a/2)^2]}$$

and the magnitude of the total force is

$$|\mathbf{F}_{\text{total}}| = 2k_0 \frac{qQ}{h^2} \sin \theta = 2k_0 \frac{qQ}{[s^2 + (a/2)^2]} \sin \theta$$

substituting $\sin \theta = \frac{a/2}{h} = \frac{a/2}{\sqrt{s^2 + (a/2)^2}}$
$$|\mathbf{F}_{\text{total}}| = 2k_0 \frac{qQ}{[s^2 + (a/2)^2]} \frac{a/2}{\sqrt{s^2 + (a/2)^2}}$$

$$|\mathbf{F}_{\text{total}}| = k_0 \frac{aqQ}{[s^2 + (a/2)^2]^{3/2}}$$

By symmetry see that \mathbf{F}_{total} is parallel to the y-axis, in $\hat{\mathbf{j}}$ direction so that

$$\left|\mathbf{F}_{\text{total}}\right| = k_0 \frac{\text{aqQ}}{\left[\text{s}^2 + (a/2)^2\right]^{3/2}} \mathbf{\hat{j}}$$

(b) The magnitude of the force between two charges q_1 , q_2 is given by Coulomb's law:

$$\mathbf{F} = \frac{1}{4\pi\varepsilon_0} \frac{\mathbf{q}_1 \mathbf{q}_2}{\mathbf{r}^2} \qquad (1)$$

where ε_0 is the permittivity of free space. The force can be seen to arise from the electric field around charge q_i

$$E = \frac{F}{q} = \frac{1}{4\pi\varepsilon_0} \frac{q_i}{r^2} \qquad (2)$$

If the charges are immersed in a medium other than free space, ε_0 is replaced in expressions (1) and (2) by the permittivity value ε of that medium. Thus, permittivity is a scaling factor for electric field strength in a medium and quantifies the electrostatic behaviour of the medium.

(c) Dielectric materials with high permittivity values are used in the production of capacitors. For example, in a parallel plate capacitor, the electric field between the plates carrying surface charge density σ is

$$E = \frac{\sigma}{\epsilon}$$

a dielectric material with permittivity $\varepsilon >> 1$ inserted between the plates lowers the electric field between the plates, thus allowing greater charge to be stored at a given potential difference, i.e. a greater value of C (farads) is obtained for a given geometry.

Other possible engineering examples: dielectric in a coaxial cable; the SiO_2 layer in CMOS microelectronics etc.

QUESTION 2

(Marks 16)

(a) The charge density varies with radius given by

$$\rho(\mathbf{r}) = -\frac{5\rho_0}{2} \left[1 - \frac{\mathbf{r}^2}{\mathbf{R}^2} \right]$$

where
$$\rho_0 = \frac{\mathbf{Q}}{(4/3\pi\mathbf{R}^3)}.$$

(i) The volume of a spherical shell of charge of thickness dr' at radius r' away from the nucleus the is

$$dV = 4\pi r'^2 dr'$$

and the charge in this shell is

$$dq = \rho(r')dV = 4\pi r'^2 \rho(r')dr'$$

Integrating from r' = 0tor' = r,

$$q(\mathbf{r}) = \int d\mathbf{q} = \int_{0}^{r} 4\pi \rho(\mathbf{r}') \mathbf{r}'^{2} d\mathbf{r}' = 4\pi \int_{0}^{r} -\frac{5\rho_{0}}{2} \left(1 - \frac{\mathbf{r}'^{2}}{\mathbf{R}^{2}}\right) \mathbf{r}'^{2} d\mathbf{r}'$$
$$= -10\pi \rho_{0} \left[\frac{1}{3}\mathbf{r}'^{3} - \frac{\mathbf{r}'^{5}}{5\mathbf{R}^{2}}\right]_{0}^{r}$$
$$= -10\pi \left(\frac{Q}{4\pi \mathbf{R}^{3}/3}\right) \left(\frac{1}{3}\mathbf{r}^{3} - \frac{\mathbf{r}^{5}}{5\mathbf{R}^{2}}\right)$$
$$= -\frac{5r^{3}Q}{2\mathbf{R}^{2}} + \frac{3r^{5}}{2\mathbf{R}^{5}}$$

The total charge as a fn. of position is charge on nucleus Q plus the electronic contribution:

$$q(r)_{total} = Q_{nuc} + q(r) = Q + \left(-\frac{5r^{3}Q}{2R^{2}} + \frac{3r^{5}}{2R^{5}}\right)$$
$$q(r)_{total} = Q_{nuc} + q(r) = Q\left(1 - \frac{5r^{3}}{2R^{2}} + \frac{3r^{5}}{2R^{5}}\right)$$

The E-field around the nucleus is symmetric: $\mathbf{E} = E(\mathbf{r})\hat{\mathbf{r}}$. Gauss' law gives

$$\int_{\text{surface}} \mathbf{E}.\mathbf{d}\mathbf{A} = \int_{\text{surface}} \mathbf{E}(\mathbf{r})\hat{\mathbf{r}}.\mathbf{d}\mathbf{A}\hat{\mathbf{r}} = \int_{\text{surface}} \mathbf{E}(\mathbf{r})\mathbf{d}\mathbf{A} = \mathbf{E}(\mathbf{r})\int_{\text{surface}} \mathbf{d}\mathbf{A} = \mathbf{E}(\mathbf{r})(4\pi\mathbf{r}^2) = \frac{\Sigma q}{\varepsilon_0}$$

(ii) In the region 0 < r < R,

$$E(r) = k_0 \frac{q(r)}{r^2} = k_0 \frac{q}{r^2} \left(1 - \frac{5r^3}{2R^2} + \frac{3r^5}{2R^5} \right)$$

At radius r = R the charge is

$$q_{R} = Q \left(1 - \frac{5r^{3}}{2R^{2}} + \frac{3r^{5}}{2R^{5}} \right) = 0$$

as it must be for a neutral atom. By Gauss' law therefore, we must have E(r) = 0 for $r \ge R$.

Question 3 (Marks 10)

The diagram shows a circular ring of uniform electric charge of radius a. The total charge on the ring is Q coulombs. Derive an expression in terms of z and a for the electric potential at a point P vertically above the centre of the ring, 0, as shown.



The potential at point P with position vector \mathbf{r} is

$$\mathbf{V} = \mathbf{k}_0 \int \frac{\mathrm{d}\mathbf{q}}{\mathbf{r}}$$

where $k_0 = \frac{1}{4\pi\epsilon_0}$. We note from the geometry that

$$r = \sqrt{a^2 + z^2}$$

and then

$$V = k_0 \int \frac{dq}{r} = \frac{1}{4\pi\epsilon_0} \int \frac{dq}{\sqrt{a^2 + z^2}}$$
$$= \frac{1}{4\pi\epsilon_0} \frac{Q}{\sqrt{a^2 + x^2}}$$
$$\epsilon_{\rm rms} = \frac{7.58 \times 10^{-3}}{\sqrt{2}} = 5.36 \times 10^{-3} \, \text{V} = 5.36 \, \text{mV}$$